





HIGH VOLTAGE SWITCHING DIODE

Features

- Fast Switching Speed: Maximum of 50 ns
- High Reverse Breakdown Voltage: 325V
- Low Leakage Current: Maximum of 50nA when V_R = 5V or Maximum of 150nA when V_R = 250V at Room Temperature
- Ultra Small Plastic SMD Package: 1.0mm x 0.6mm x 0.5mm
- Lead, Halogen and Antimony Free, RoHS Compliant (Note 1)
- "Green" Device (Note 2)

Mechanical Data

- Case: X1-DFN1006-2
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish NiPdAu over Copper leadframe. Solderable per MIL-STD-202, Method 208
- Weight: 0.0009 grams (approximate)

X1-DFN1006-2







Device Schematic

Ordering Information (Note 3)

Part Number	Case	Packaging
BAS521LP-7	X1-DFN1006-2	3,000/Tape & Reel
BAS521LP-7B	X1-DFN1006-2	10,000/Tape & Reel

Notes:

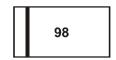
- 1. No purposefully added lead. Halogen and Antimony Free.
- 2. Diodes Inc.'s "Green" policy can be found on our website at http://www.diodes.com.
- 3. For packaging details, go to our website at http://www.diodes.com.

Marking Information

BAS521LP-7

• 98

Top View Dot Denotes Cathode Side BAS521LP-7B



Top View Bar Denotes Cathode Side 98 = Product Type Marking Code



Maximum Ratings @T_A = 25°C unless otherwise specified

Characteristic	Symbol	Value	Unit
Repetitive Peak Reverse Voltage	V _{RRM}	325	V
Working Peak Reverse Voltage DC Blocking Voltage	V_{RWM} V_{R}	325	V
Forward Current (Note 4)	I _F	400	mA
Non-Repetitive Peak Forward Surge Current @ t = 1.0μs	I _{FSM}	8.0	Α
Repetitive Peak Forward Current @ t=8.3ms (Note 4)	I _{FRM}	3.0	Α

Thermal Characteristics

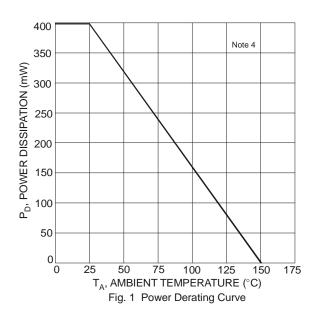
Characteristic	Symbol	Value	Unit
Power Dissipation (Note 4)	P_{D}	400	mW
Thermal Resistance Junction to Ambient Air (Note 4)	$R_{ hetaJA}$	312	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-65 to +150	°C

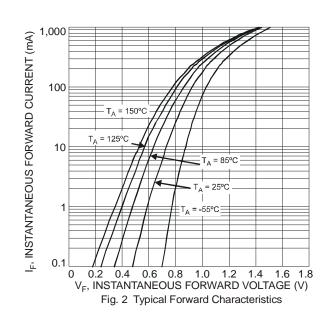
Electrical Characteristics @TA = 25°C unless otherwise specified

Characteristic	Symbol	Min	Max	Unit	Test Condition
Reverse Breakdown Voltage (Note 5)	$V_{(BR)R}$	300	_	V	$I_R = 100 \mu A$
Forward Voltage	V _F	_	1.1	V	I _F = 100mA
		_	50	nA	$V_R = 5V$
Reverse Current (Note 5)	I _R	_	150	nA	$V_R = 250V$
			100	μΑ	$V_R = 250V, T_J = 150^{\circ}C$
Total Capacitance	C _T		5	pF	$V_R = 0, f = 1.0MHz$
Reverse Recovery Time	+	t _{rr} —	50	ns	$I_F = I_R = 30 \text{mA},$
	ιπ				$I_F = I_R = 30 \text{mA},$ $I_{rr} = 0.1 \times I_R, R_L = 100 \Omega$

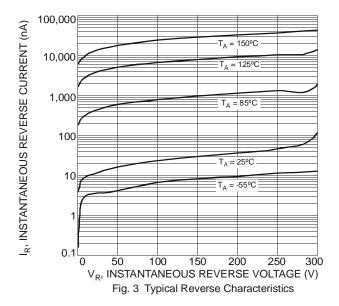
Notes:

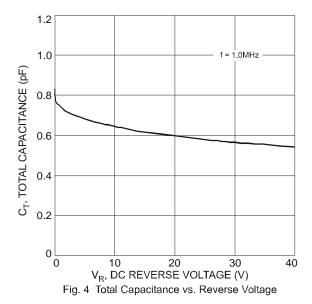
- 4. Part mounted on FR-4 board with recommended pad layout, which can be found on our website at http://www.diodes.com.
- 5. Short duration pulse test used to minimize self-heating effect.



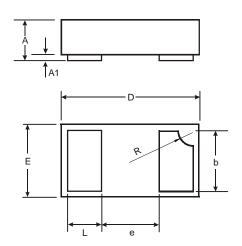






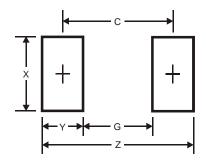


Package Outline Dimensions



X1-DFN1006-2					
Dim	Min	Max	Тур		
Α	0.47	0.53	0.50		
A1	0	0.05	0.03		
b	0.45	0.55	0.50		
D	0.95	1.075	1.00		
Е	0.55	0.675	0.60		
е	-	-	0.40		
L	0.20	0.30	0.25		
R	0.05	0.15	0.10		
All Dimensions in mm					

Suggested Pad Layout



Dimensions	Value (in mm)		
Z	1.1		
G	0.3		
Х	0.7		
Υ	0.4		
С	0.7		



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